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Substitute for	Form 1449A/PTO	AL GARD	Application Number	10/811,112			
INFORMATIO	N DISCLOSURE		Filing Date	March 26, 2004			
STATEMENT	BY APPLICANT		First Named Inventor	DiplIng. Daniel Supper			
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1	of	1	Attorney Docket No.	MAIKP128US			

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AKS	CA	"Transverse Mode Selection in Large-Area Oxide-Confined Vertical-Cavity Surface-Emitting Lasers Using a Shallow Surface Relief", H. MARTINSSON, J.A. VUKUSIC, M. GRABHERR, M. MICHALZIK, R. JÄGER, K.J. EBELING, and A. LARSSON, IEEE Photonics Technology Letter, Vol. 11, No. 12, December 1999, pgs. 1536-1538.	
AKS	СВ	"Increased-area oxidized single-fundamental mode VCSEL with self-aligned shallow etched surface relief", H.J. UNOLD, M. GRABHERR, F. EBERHARD, F. MEDERER, R. JÄGER, M. RIEDL, and K.J. EBELING, Electronics Letters, 5 th August 1999, Vol. 35, No. 16, pgs. 1340-1341.	······································
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